# **GP1S39**

#### ■ Features

1. Ultra-compact package

2. PWB mounting type

3. Double-phase phototransistor output type for detecting of rotation direction and count

4. Wide gap between light emitter and detector: 1.5mm

5. Slit width: 0.8mm 6. Detecting pitch: 0.6mm

### ■ Applications

1. Mouses

2. Cameras

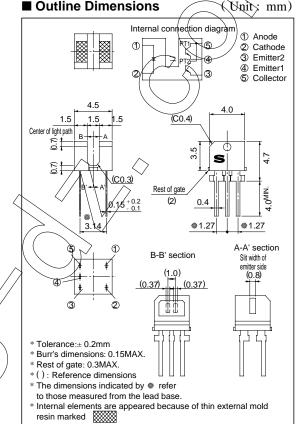
■ Absolute Maximum Ratings

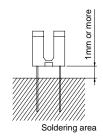
	Parameter	Symbol	Rating	) Unit
	Forward current	$I_F$	50 <	mΑ
Input	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	P	75	mW
	Collector-emitter voltage	V <sub>CE10</sub>	35	V
Output	Emitter-collector voltage	$V_{E_1CO}$ $V_{E_2CO}$	6	V
	Collector current	Ic	20	mA
	Collector power dissipation	Pc	75	mW
	Total power dissipation	P tot	100	mW
	Operating temperature	$T_{opr}$	- 25 to + 85	°C
	Storage temperature	Tstg	- 40 to + 100	°C
*Soldering temperature		$T_{sol}$	260	°C

<sup>\*1</sup> For 5 seconds

# Subminiature, Double-phase **Output, Wide Gap Photointerrupter**

**■** Outline Dimensions





## **■** Electro-optical Characteristics

Parameter		Symbol	Conditions	MIN.	TYP.	MAX. Unit	
Input	Forward voltage		V <sub>F</sub>	$I_F = 20mA$	-	1.2	1(4 V
	Reverse current		$I_R$	$V_R = 3V$	-	-	10 pA
Output	Collector dark current		I <sub>CEO</sub>	$V_{CE} = 20V$	-		100 nA
Transfer charact- eristics	Collector current		$I_{\rm C}$	$V_{CE} = 5V$ , $I_F = 4mA$	130	[-(	520 μA
	Collector current ratio		$I_{C1}/I_{C2}$	$V_{CE} = 5V$ , $I_F = 4mA$	0.67	-/	1,5/ -
	Collector-emitter saturati	on voltage	V <sub>CE(sat)</sub>	$I_F = 8mA$ , $I_C = 50 \mu A$	- /	- ·	0.4 V
	Response time Rise time Fall time	t <sub>r</sub>	$V_{CE} = 5V$ , $I_{C} = 100 \mu A$	1	50	150 μs	
		Fall time	t <sub>f</sub>	$R_L = 1~000~\Omega$	- (	50)	150 μs

Fig. 1 Forward Current vs. Ambient Temperature

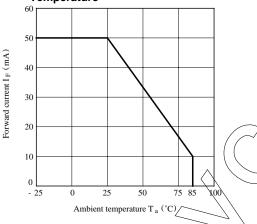


Fig. 3 Forward Current vs. Forward Voltage

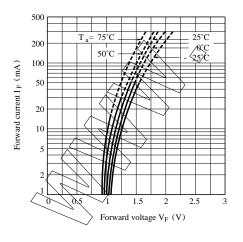


Fig. 2 Power Dissipation vs.

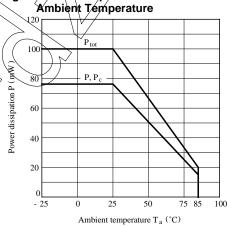


Fig. 4 Collector Current vs.
Forward Current

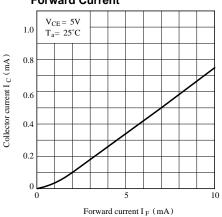


Fig. 5 Collector Current vs.
Collector-emitter Voltage

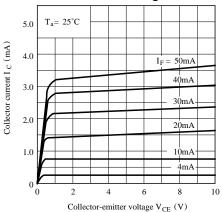


Fig. 7 Collector-emitter Saturation Voltage vs. Ambient Temperature

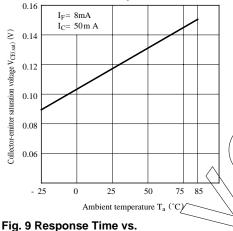


Fig. 9 Response Time vs. Load Resistance

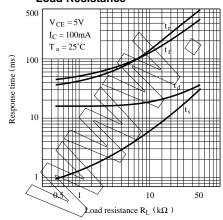


Fig. 6 Collector Current vs.
Ambient Temperature

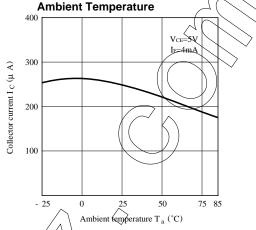
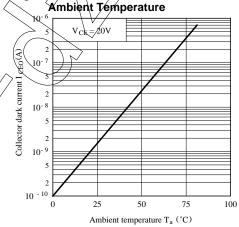


Fig. 8 Collector Dark Current vs.



### **Test Circuit for Response Time**

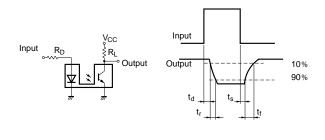
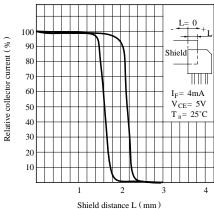


Fig.10 Relative Collector Current vs. Shield Distance (1)



• Please refer to the chapter "Precautions for Use".

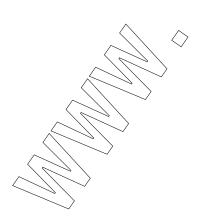
Fig.11 Relative Collector Current vs.
Shield Distance (2)

Shield Distance (2)

Shield VCE = 5V

Ta=25°C

Shield distance L (mm)



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- Alarm equipment
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